

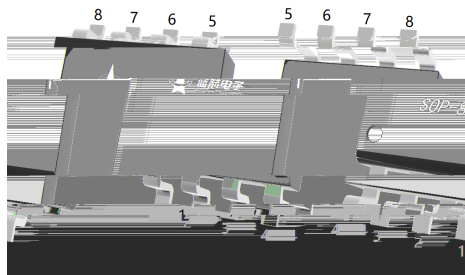
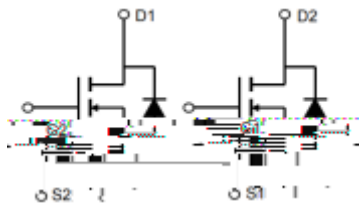
Rev.A Aug.-2023

SOP-8 N MOS

Double N-CHANNEL MOSFET in a SOP-8 Plastic Package.

$V_{DS}(V)=30V$ $I_D=16A$
 $R_{DS(ON)}@10V<8m\Omega$ (Typ. 7.6mR)
 $R_{DS(ON)}@4.5V<12m\Omega$ (Typ. 10.8mR)
 HF Product.

MB/NB/UMPC/VGA , DC-DC ,
 High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA,
 Networking DC-DC Power System, Load Switch.



PIN1	S1	PIN 2	G1	PIN 3	S2	PIN 4	G2
PIN 5	D2	PIN 6	D2	PIN 7	D1	PIN 8	D1

See Marking Instructions.

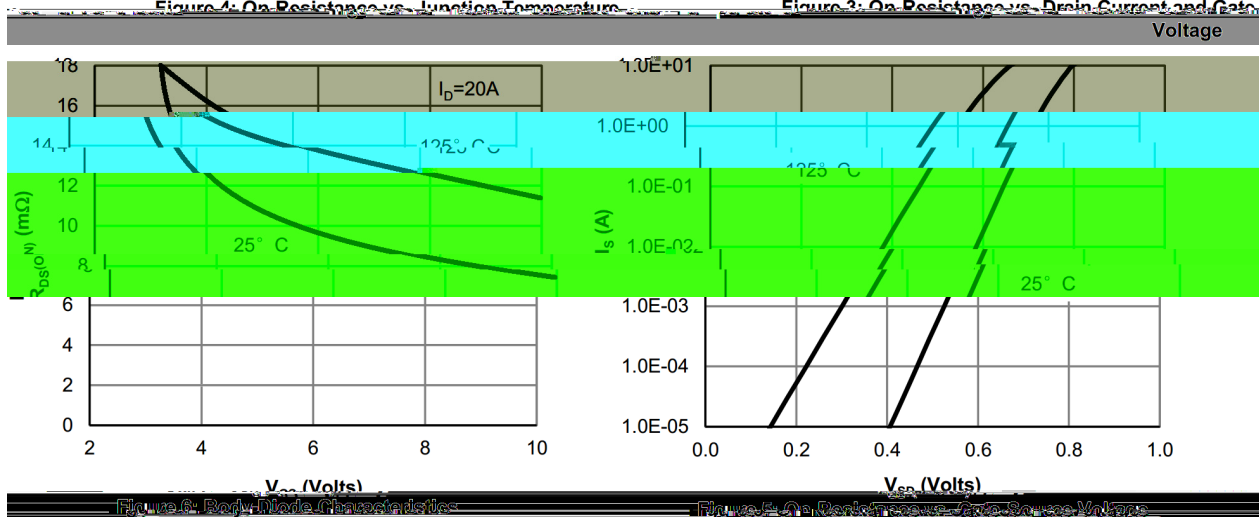
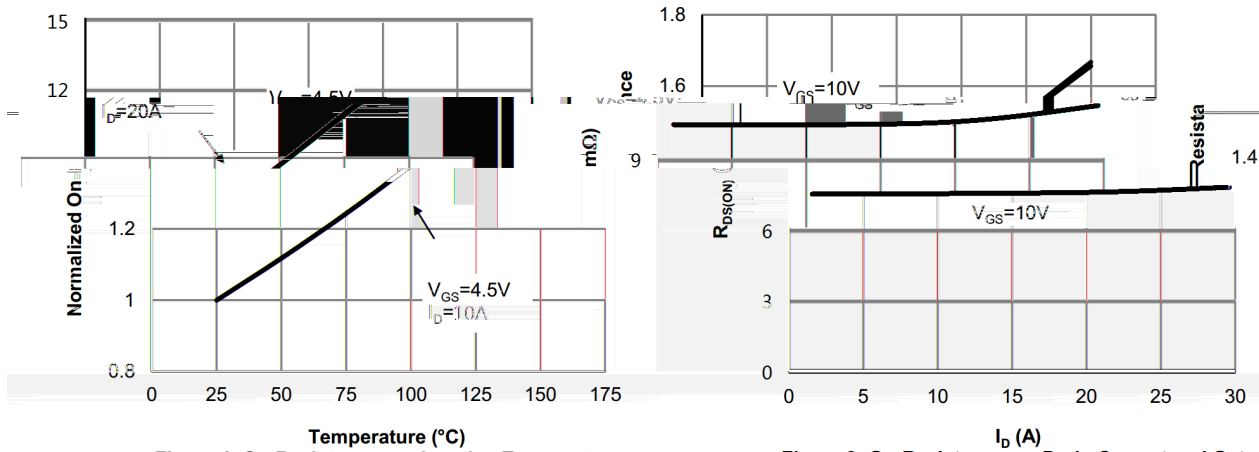
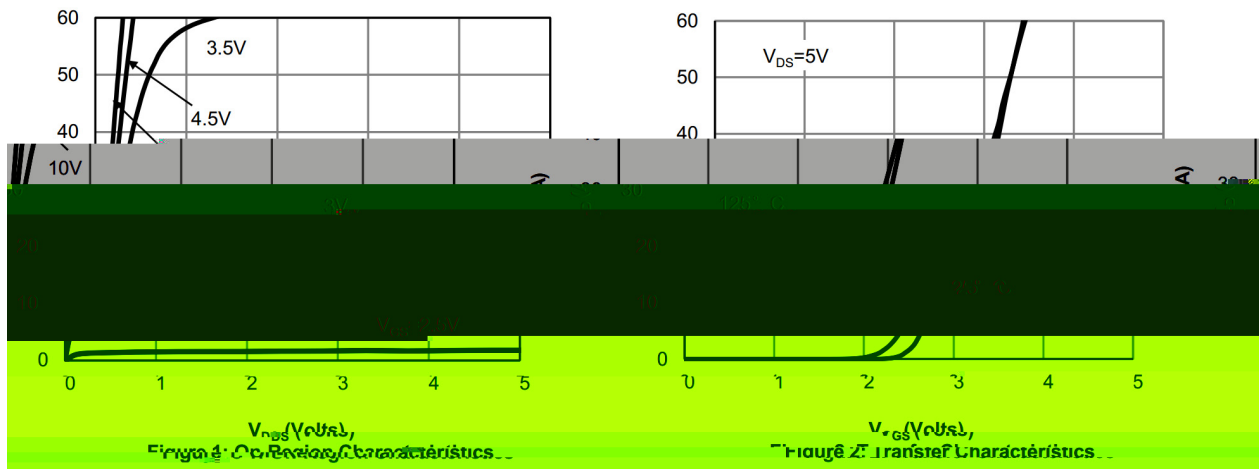
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	16	A
Pulsed Drain Current	I_{DM}	59	A
Power Dissipation	P_D	3.2	W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	
Maximum Junction-to-Ambient	$R_{JA}(\text{Steady-State})$	39	/W

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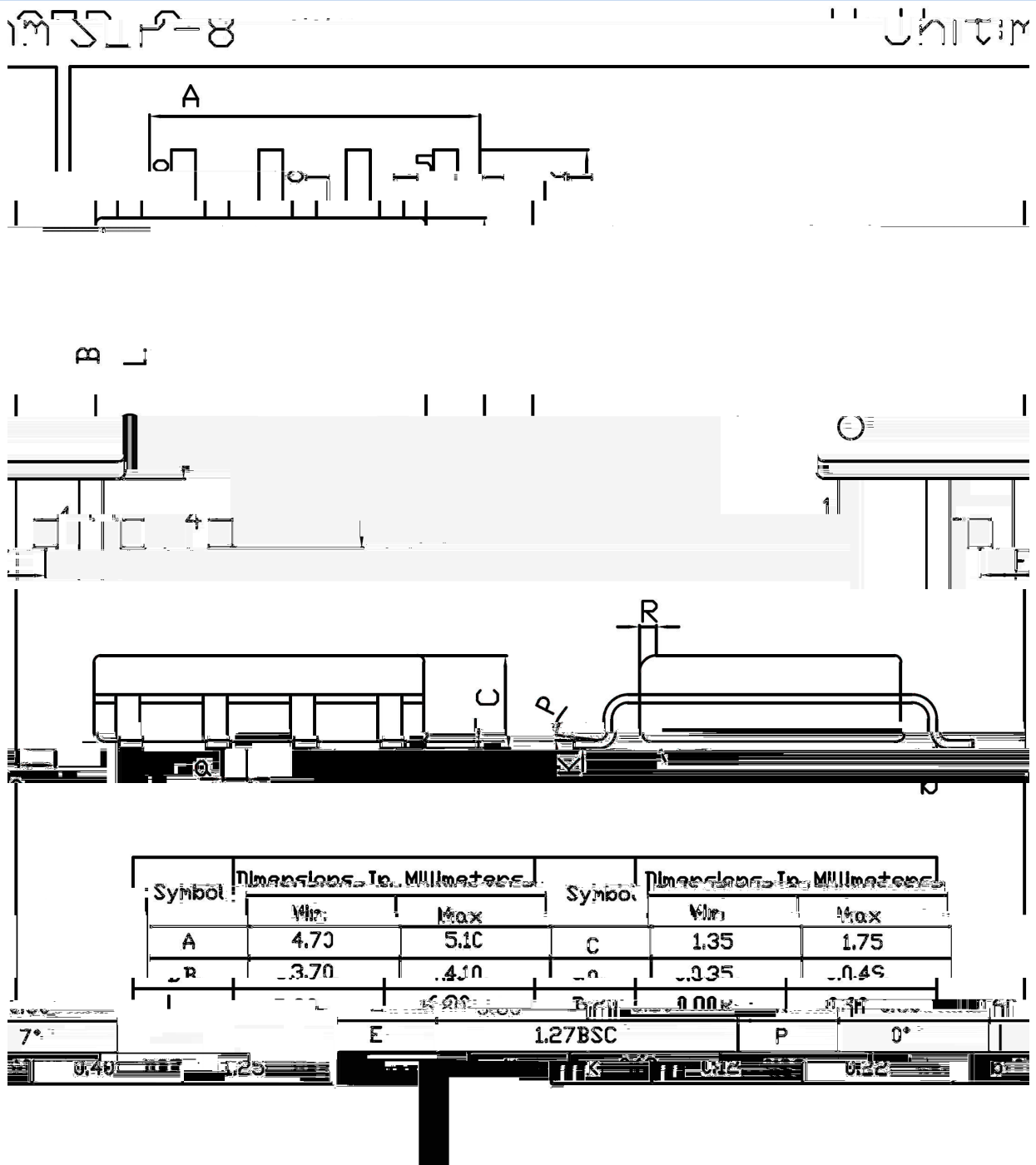
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DS}	$V_{GS}=0V$ $I_D=250\mu A$	30	35		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V$ $V_{GS}=0V$			1	μA
Gate-Body leakage current	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	1.0	1.7	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=20A$		7.6	8	m Ω
		$V_{GS}=4.5V$ $I_D=10A$		10.8	12	m Ω
Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=1.0A$			1.2	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		1170		pF
Output Capacitance	C_{oss}			110		pF
Reverse Transfer Capacitance	C_{rss}			100		pF
Gate resistance	R_g	$V_{DS}=0V$ $V_{GS}=0V$ $f=1.0MHz$		3.7		Ω
Total Gate Charge	$Q_{g(10V)}$	$V_{GS}=10V$ $V_{DS}=15V$ $I_D=20A$		40		nC
Total Gate Charge	$Q_{g(4.5V)}$			22		nC
Gate-Source Charge	Q_{gs}			11		nC
Gate-Drain Charge	Q_{gd}			5		nC

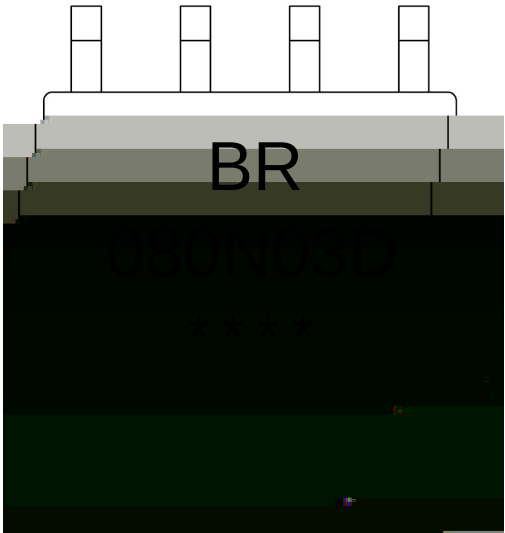
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Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=15\text{ V}$ $V_{GS}=10\text{V}$ $R_L=0.75\Omega$ $R_{GEN}=3\Omega$		11		ns
Turn-On Rise Time	t_r			14		ns
Turn-Off Delay Time	$t_{d(off)}$			38		ns
Turn-Off Fall Time	t_f			10		ns



Rev.A Aug.-2023





BR
080N03D

Note:

BR:	Company Code
080N03D:	Product Type
****:	Lot No. Code, code change with Lot No

Temperature Profile for IR Reflow Soldering(Pb-Free)

Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 150 | 180 | 60 | 90sec; | 1.Preheating:150~180 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

260±5	10±1 sec.	Temp.:260±5	Time:10±1 sec
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/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel /	Reels/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Reel	Inner Box	Outer Box
SOP/ESOP-8	4,000	2	8,000	6	48,000	13 ×12	360×360×50	380×335×366